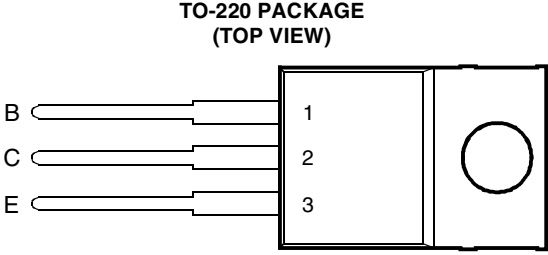




- Rugged Epitaxial Planar Construction
- 10 A Continuous Collector Current
- Operating Characteristics Fully Guaranteed at 100°C
- t_{xo} typically 320 ns, $I_C = 10$ A



Pin 2 is in electrical contact with the mounting base. MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING | | SYMBOL | VALUE | UNIT |
|---|----------|-----------|-------------|------|
| Collector-base voltage ($I_E = 0$) | TIPL790 | V_{CBO} | 150 | V |
| | TIPL790A | | 200 | |
| Collector-emitter voltage ($V_{BE} = 0$) | TIPL790 | V_{CES} | 150 | V |
| | TIPL790A | | 200 | |
| Collector-emitter voltage ($I_B = 0$) | TIPL790 | V_{CEO} | 120 | V |
| | TIPL790A | | 150 | |
| Emitter-base voltage | | V_{EBO} | 8 | V |
| Continuous collector current | | I_C | 10 | A |
| Peak collector current (see Note 1) | | I_{CM} | 15 | A |
| Continuous device dissipation at (or below) 25°C case temperature | | P_{tot} | 70 | W |
| Operating junction temperature range | | T_j | -65 to +150 | °C |
| Storage temperature range | | T_{stg} | -65 to +150 | °C |

NOTE 1: This value applies for $t_p \leq 10$ ms, duty cycle $\leq 2\%$.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | | | | MIN | TYP | MAX | UNIT |
|---|--|--|--|--|------------|-----|--------------------------|---------------|
| $V_{CEO(sus)}$ Collector-emitter sustaining voltage | $I_C = 100 \text{ mA}$ | $L = 25 \text{ mH}$ | (see Note 2) | TIPL790 TIPL790A | 120 150 | | | V |
| V_{CBO} Collector-base breakdown voltage | $I_C = 1 \text{ mA}$ | | (see Note 3) | TIPL790 TIPL790A | 150 200 | | | V |
| I_{CES} Collector-emitter cut-off current | $V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$ $V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$ | $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ | $T_C = 100^\circ\text{C}$ $T_C = 100^\circ\text{C}$ | TIPL790 TIPL790A TIPL790 TIPL790A | | | 0.05 0.05 1 1 | mA |
| I_{CEV} Collector cut-off current | $V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$ | $1.5 < V_{EB} < 8 \text{ V}$ | | TIPL790 TIPL790A | | | 50 50 | μA |
| I_{CEO} Collector cut-off current | $V_{CE} = 120 \text{ V}$ $V_{CE} = 150 \text{ V}$ | $I_B = 0$ $I_B = 0$ | | TIPL790 TIPL790A | | | 50 50 | μA |
| I_{EBO} Emitter cut-off current | $V_{EB} = 5 \text{ V}$ | $I_C = 0$ | | | | | 4 | mA |
| h_{FE} Forward current transfer ratio | $V_{CE} = 5 \text{ V}$ | $I_C = 0.5 \text{ A}$ | (see Notes 3 and 4) | | 60 | | 500 | |
| $V_{CE(sat)}$ Collector-emitter saturation voltage | $I_B = 20 \text{ mA}$ $I_B = 30 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 50 \text{ mA}$ | $I_C = 4 \text{ A}$ $I_C = 7 \text{ A}$ $I_C = 10 \text{ A}$ $I_C = 10 \text{ A}$ | (see Notes 3 and 4) $T_C = 100^\circ\text{C}$ | | | | 1.2 1.5 2.0 2.0 | V |
| $V_{BE(sat)}$ Base-emitter saturation voltage | $I_B = 20 \text{ mA}$ $I_B = 30 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 50 \text{ mA}$ | $I_C = 4 \text{ A}$ $I_C = 7 \text{ A}$ $I_C = 10 \text{ A}$ $I_C = 10 \text{ A}$ | (see Notes 3 and 4) $T_C = 100^\circ\text{C}$ | | | | 1.8 1.9 2.2 2.1 | V |
| V_{EC} Parallel diode forward voltage | $I_E = 10 \text{ A}$ | $I_B = 0$ | | | | | 3 | V |
| f_t Current gain bandwidth product | $V_{CE} = 10 \text{ V}$ | $I_C = 0.5 \text{ A}$ | $f = 1 \text{ MHz}$ (see Note 5) | | | 10 | | MHz |
| C_{ob} Output capacitance | $V_{CB} = 20 \text{ V}$ | $I_E = 0$ | $f = 0.1 \text{ MHz}$ | | | 90 | | pF |

- NOTES: 2. Inductive loop switching measurement.
 3. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.
 4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.
 5. To obtain f_t the $[h_{FE}]$ response is extrapolated at the rate of -6 dB per octave from $f = 1 \text{ MHz}$ to the frequency at which $[h_{FE}] = 1$.

thermal characteristics

| PARAMETER | MIN | TYP | MAX | UNIT |
|---|-----|-----|------|--------------------|
| $R_{\theta JC}$ Junction to case thermal resistance | | | 1.79 | $^\circ\text{C/W}$ |

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

| PARAMETER | TEST CONDITIONS † | | | | MIN | TYP | MAX | UNIT |
|-------------------------------|---|---|-----------------------|--|-----|-----|-----|------|
| t_{si} Current storage time | $I_C = 10 \text{ A}$ $I_{B(off)} = -2.5 \text{ A}$ | $I_{B(on)} = 50 \text{ mA}$ $V_{BE(off)} = -5 \text{ V}$ | (see Figures 1 and 2) | | 450 | 700 | ns | |
| t_{rv} Voltage rise time | | | | | 160 | 750 | ns | |
| t_{fi} Current fall time | | | | | 250 | 400 | ns | |
| t_{ti} Current tail time | | | | | 280 | 450 | ns | |
| t_{xo} Cross over time | | | | | 320 | 500 | ns | |

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PARAMETER MEASUREMENT INFORMATION

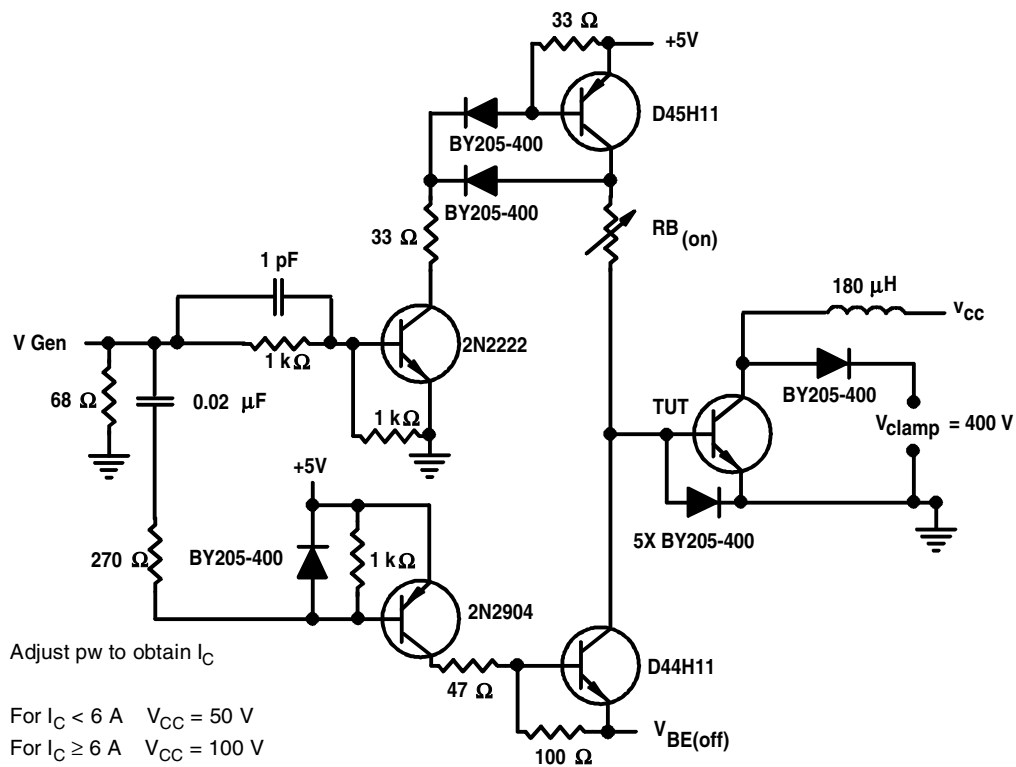
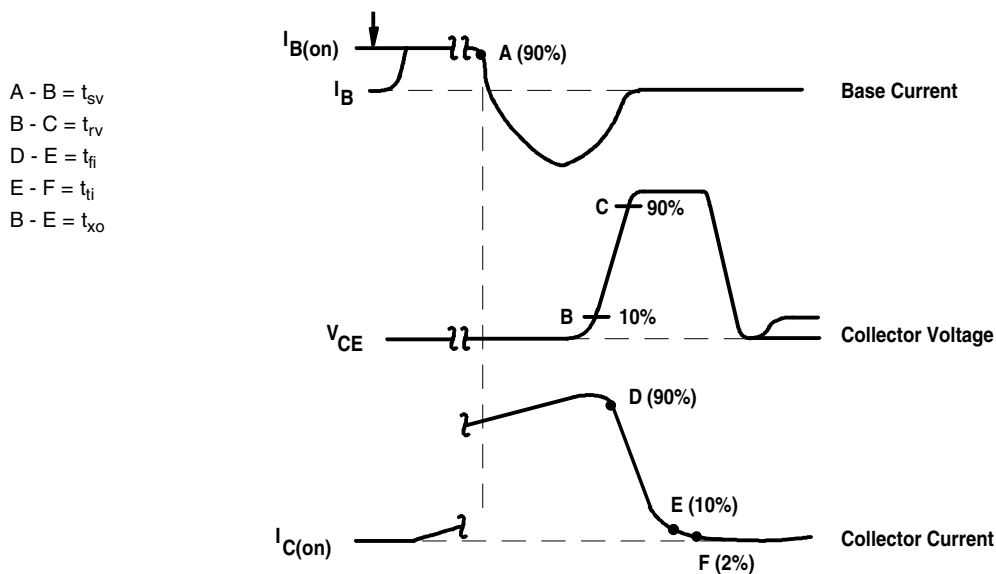


Figure 1. Inductive-Load Switching Test Circuit



NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics: $t_r < 15\text{ ns}$, $R_{in} > 10\ \Omega$, $C_{in} < 11.5\text{ pF}$.
 B. Resistors must be noninductive types.

Figure 2. Inductive-Load Switching Waveforms

PRODUCT INFORMATION

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN
VS
COLLECTOR CURRENT

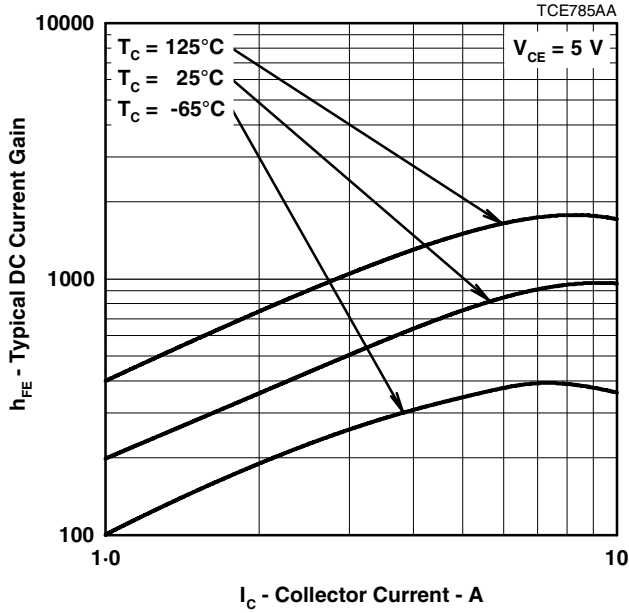


Figure 3.

COLLECTOR-EMITTER SATURATION VOLTAGE
VS
BASE CURRENT

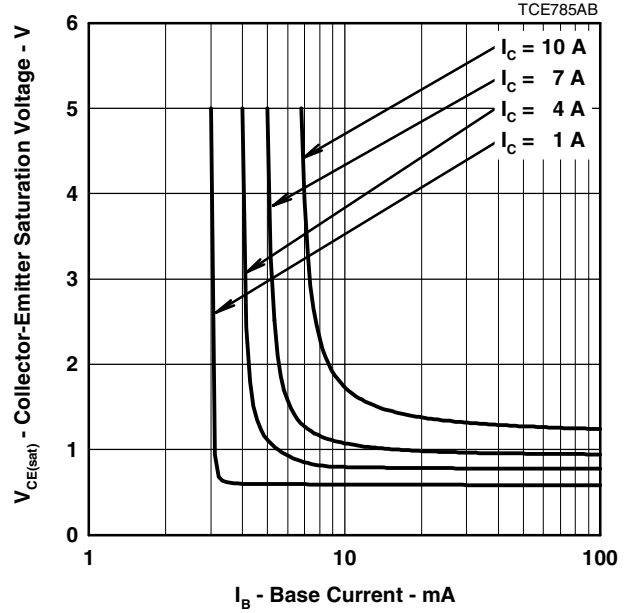


Figure 4.

BASE-EMITTER SATURATION VOLTAGE
VS
BASE CURRENT

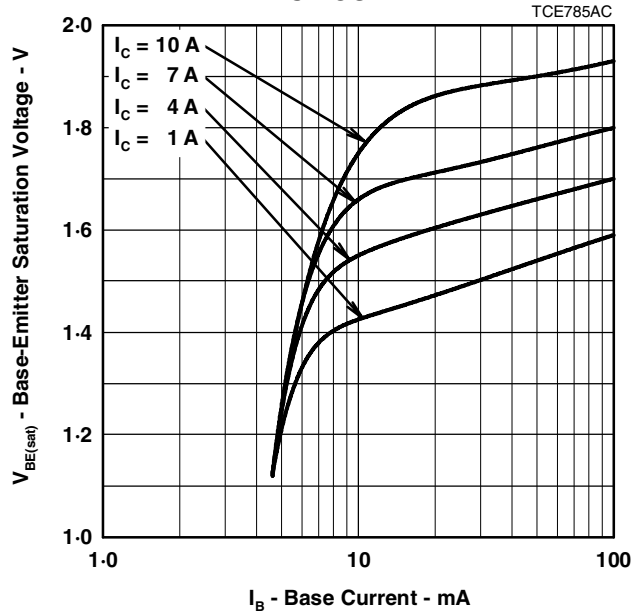


Figure 5.

COLLECTOR CUT-OFF CURRENT
VS
CASE TEMPERATURE

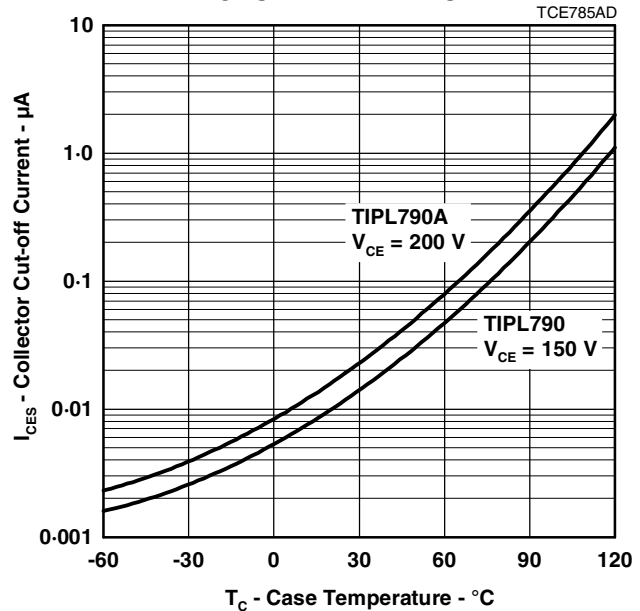


Figure 6.

PRODUCT INFORMATION

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MAXIMUM SAFE OPERATING REGIONS

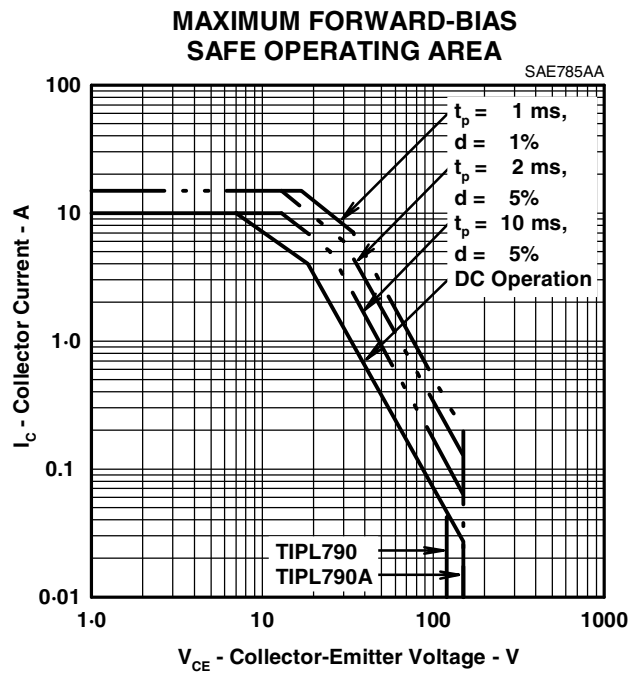


Figure 7.

PRODUCT INFORMATION

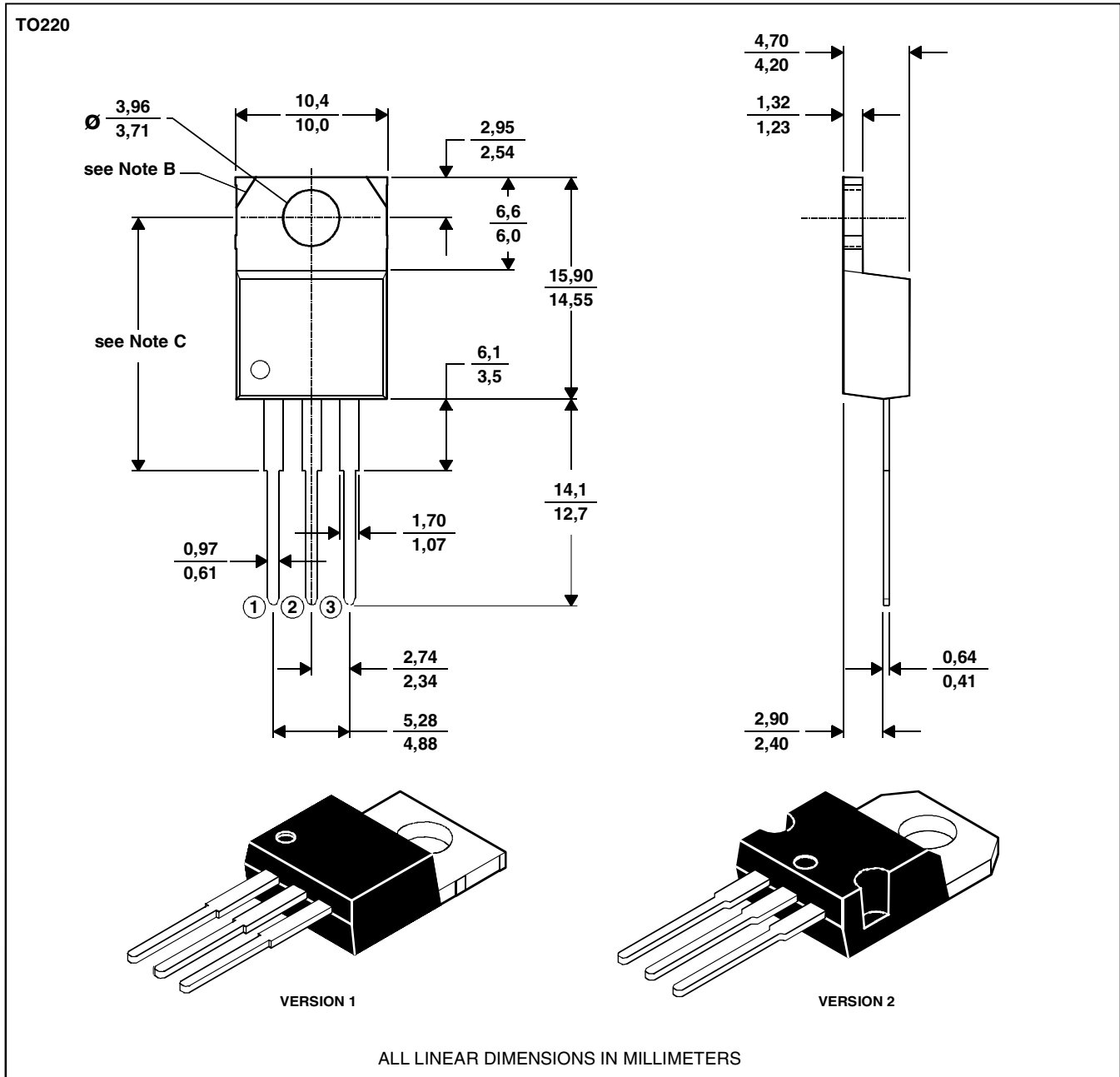
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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.
B. Mounting tab corner profile according to package version.
C. Typical fixing hole centre stand off height according to package version.
Version 1, 18.0 mm. Version 2, 17.6 mm.

MDXXBE

PRODUCT INFORMATION

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